

SOT-23 Formed SMD Package

CMBT5087

SILICON PLANAR EPITAXIAL TRANSISTORS

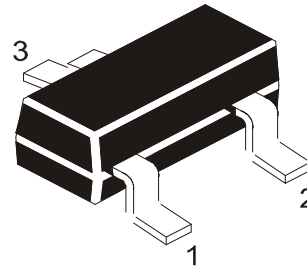
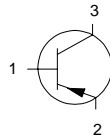
PNP transistor

Marking

CMBT5087= 2Q

Pin configuration

1 = BASE
2 = EMITTER
3 = COLLECTOR



ABSOLUTE MAXIMUM RATINGS

Collector-base voltage (open emitter)	V_{CBO}	max.	50 V
Collector-emitter voltage (open base)	V_{CEO}	max.	50 V
Emitter-base voltage (open collector)	V_{EBO}	max.	3 V
Collector current	I_C	max.	50 mA
Total power dissipation at $T_{amb} = 25^\circ\text{C}$	P_{tot}^*	max.	225 mW
Junction temperature	T_j	max.	150 °C
D.C. current gain	h_{FE}	min.	250
$-I_C = 100 \mu\text{A}; V_{CE} = 5 \text{ V}$		max.	800
Transition frequency at $f = 20 \text{ MHz}$	f_T	min.	40 MHz
$I_C = 500 \mu\text{A}; V_{CE} = 5 \text{ V}$			

RATINGS (at $T_A = 25^\circ\text{C}$ unless otherwise specified)

Limiting values

Collector-base voltage (open emitter)	V_{CBO}	max.	50 V
Collector-emitter voltage (open base)	V_{CEO}	max.	50 V

*FR-5 Board = $1.0 \times 0.75 \times 0.062 \text{ in.}$

CMBT5087

Emitter-base voltage (open collector)	V_{EBO}	max.	3 V
Collector current (d.c.)	I_C	max.	50 mA
Total power dissipation at $T_{amb} = 25^\circ\text{C}$	P_{tot}^*	max.	225 mW
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$
Junction temperature	T_j	max.	150 $^\circ\text{C}$

THERMAL RESISTANCE

From junction to ambient	$R_{th\ j-a}$	417	$^\circ/\text{W}$
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CHARACTERISTICS (at $T_A = 25^\circ\text{C}$ unless otherwise specified)

Collector cut-off current

$I_E = 0; V_{CB} = 10\text{ V}$	I_{CBO}	max.	10 nA
$I_E = 0; V_{CB} = 35\text{ V}$		max.	50 nA

Breakdown voltages

$I_C = 1\text{ mA}; I_B = 0$	V_{CEO}	min.	50 V
$I_C = 100\text{ }\mu\text{A}; I_E = 0$	V_{CBO}	min.	50 V

Saturation voltage

$I_C = 10\text{ mA}; I_B = 1.0\text{ mA}$	V_{CEsat}	max.	300 mV
$I_C = 10\text{ mA}; I_B = 1.0\text{ mA}$	V_{BEsat}	max.	0.85 V

D.C. current gain

$I_C = 100\text{ }\mu\text{A}; V_{CE} = 5\text{ V}$	h_{FE}	min.	250
		max.	800
$I_C = 1\text{ mA}; V_{CE} = 5\text{ V}$		min.	250
$I_C = 10\text{ mA}; V_{CE} = 5\text{ V}$		min.	250

Collector capacitance at $f = 100\text{ KHz}$

$I_E = 0; V_{CB} = 5\text{ V}$	C_{ob}	max.	4.0 pF
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Transition frequency at $f = 20\text{ MHz}$

$I_C = 500\text{ }\mu\text{A}; V_{CE} = 5\text{ V}$	f_T	min.	40 MHz
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Small signal current

$I_C = 1\text{ mA}; V_{CE} = 5\text{ V}; f = 1\text{ KHz}$	h_{fe}	min.	250
		max.	900

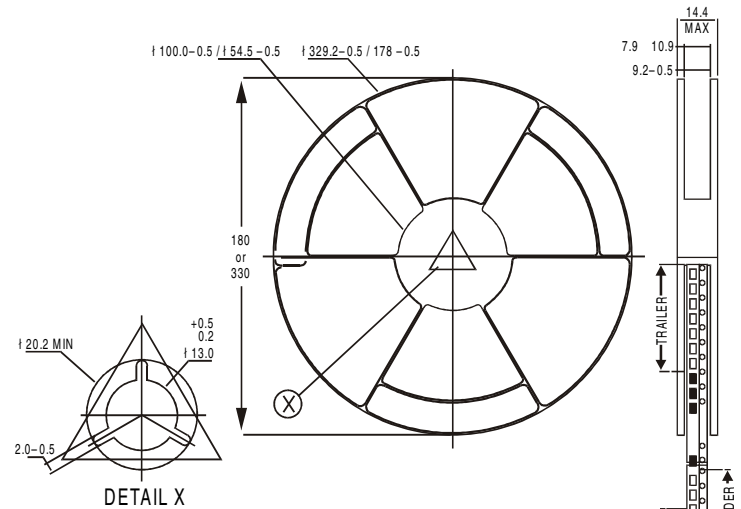
Noise figure

$I_C = 20\text{ }\mu\text{A}; V_{CE} = 5\text{ V}; R_S = 10\text{ k}\Omega$	N_F	max.	2.0 dB
$f = 10\text{ Hz to } 15.7\text{ KHz}$			
$I_C = 100\text{ }\mu\text{A}; V_{CE} = 5\text{ V}; R_S = 3.0\text{ k}\Omega; f = 1.0\text{ KHz}$	N_F	max.	2.0 dB

*FR-5 Board = $1.0 \times 0.75 \times 0.62\text{ in.}$

SOT-23 Package Reel Information

Reel specifications for Packing (13"/7" reels)



	8mm Tape	8mm Tape
	Size of Reel	Size of Reel
	330 mm (13")	180 mm (7")
No. of Devices	10,000 Pcs	3,000 Pcs

- ## Tape Specification for SOT-23 Surface Mount Device



Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
SOT-23 T&R	3K/reel	136 gm/3K pcs	3" x 7.5" x 7.5"	12.0K	17" x 15" x 13.5"	192.0K	12 kgs
			9" x 9" x 9"	51.0K	19" x 19" x 19"	408.0K	28 kgs
	10K/reel	415 gm/10K pcs	13" x 13" x 0.5"	10.0K	17" x 15" x 13.5"	300.0K	16 kgs

Customer Notes

Component Disposal Instructions

1. CDIL Semiconductor Devices are RoHS compliant, customers are requested to please dispose as per prevailing Environmental Legislation of their Country.
2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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